



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**Application No.:** 

10/076,055

Filing Date:

February 14, 2002

Applicant:

Takizawa

**Group Art Unit:** 

2811

Examiner:

Thien F. Tran

Title:

A SEMICONDUCTOR DEVICE INCLUDING AN

INSULATED GATE FIELD EFFECT TRANSISTOR

(as amended)

Attorney Docket:

9319S-000329

Mail Stop Non-Fee Amendment
Director of the United States Patent and Trademark Office
P.O. Box 1450
Alexandria, VA 22313-1450

## <u>AMENDMENT</u>

Sir:

In response to the Office Action mailed <u>June 12, 2003</u>, please amend the application as follows and consider the remarks set forth below.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Remarks begin on page 5 of this paper.

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